



UTG40N120LMD1

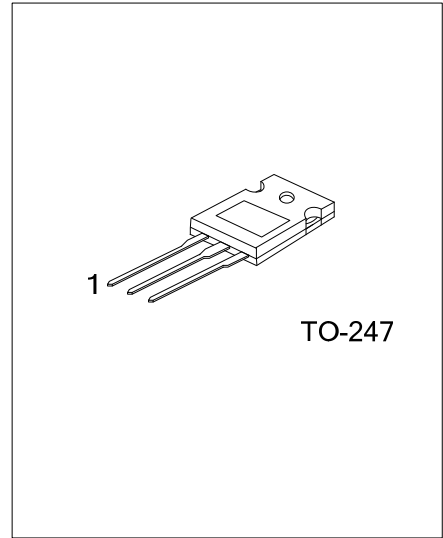
Insulated Gate Bipolar Transistor

1200V TRENCH GATE FIELD-STOP IGBT

DESCRIPTION

The UTC **UTG40N120LMD1** is a Trench Field-Stop Insulated Gate Bipolar Transistor. it uses UTC's advanced technology to provide customers with high switching speed, low saturation voltage and low switching loss, etc.

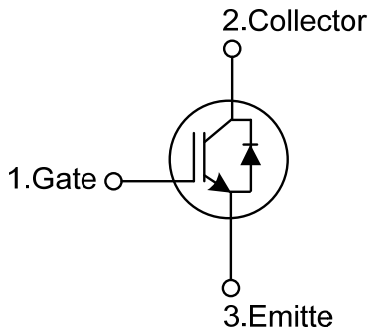
The UTC **UTG40N120LMD1** is suitable for the resonant or soft switching applications.



FEATURES

- * High switching speed
- * High avalanche ruggedness
- * Low saturation voltage: $V_{CE(SAT),Typ.} = 1.5V @ I_C=40A, V_{GE}=15V$ ($T_C = 25^\circ C$)

SYMBOL



ORDERING INFORMATION

Ordering Number		Package	Pin Assignment			Packing
Lead Free	Halogen Free		1	2	3	
UTG40N120LMD1L-T47-T	UTG40N120LMD1G-T47-T	TO-247	G	C	E	Tube

Note: Pin Assignment: G: Gate C: Collector E: Emitter

UTG40N120LMD1G-T47-T 	(1)Packing Type (2)Package Type (3)Green Package	(1) T: Tube (2) T47: TO-247 (3) G: Halogen Free and Lead Free, L: Lead Free
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■ ABSOLUTE MAXIMUM RATINGS (T_A=25°C, unless otherwise specified)

PARAMETER	SYMBOL	RATINGS	UNIT	
Collector-Emitter Voltage	V _{CES}	1200	V	
Gate-Emitter Voltage	V _{GES}	±20	V	
Transient Gate-emitter voltage (t _p < 5 ms)		±25	V	
Continuous Collector Current	I _C	T _C =25°C	80	A
		T _C =100°C	40	A
Collector Current Pulsed (Note 1)	I _{CM}	160	A	
Diode Forward Current	I _F	T _C =25°C	80	A
		T _C =100°C	40	A
Short Circuit Withstand Time V _{GE} = 15V, V _{CC} ≤ 200V Allowed number of short circuits < 1000 Time between short circuits: ≥ 1.0s T _{VJ} = 25°C	t _{SC}	8	μs	
Power Dissipation (T _C =25°C)	P _D	285	W	
Operating Junction Temperature	T _J	-40 ~ +150	°C	
Storage Temperature Range	T _{STG}	-55 ~ +150	°C	

Notes: 1. Absolute maximum ratings are stress ratings only and functional device operation is not implied.
Absolute maximum ratings are those values beyond which the device could be permanently damaged.
2. Pulse width limited by maximum junction temperature.

■ THERMAL DATA

PARAMETER	SYMBOL	RATING	UNIT
Junction to Case	θ _{JC}	0.44	°C/W

■ ELECTRICAL CHARACTERISTICS (T_c=25°C, unless otherwise specified)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT	
Off Characteristics							
Collector-Emitter Breakdown Voltage	BV _{CES}		1200			V	
Collector Cut-Off Current	I _{CES}	V _{CE} =1200V, V _{GE} =0V			5	μA	
G-E Leakage Current	I _{GES}	V _{CE} =0V, V _{GE} =±20V			±400	nA	
On Characteristics							
Gate to Emitter Threshold Voltage	V _{GE(TH)}	I _C =250μA, V _{CE} =V _{GE}	4.5		7.5	V	
Collector to Emitter Saturation Voltage	V _{CE(SAT)}	I _C =40A, V _{GE} =15V	T _C =25°C	1.5	2.0	V	
			T _C =125°C	1.8		V	
Dynamic Characteristics							
Input Capacitance	C _{IES}	V _{CE} =25V, V _{GE} =0V, f=1MHz		2520		pF	
Output Capacitance	C _{OES}			231		pF	
Reverse Transfer Capacitance	C _{RES}			60		pF	
Switching Characteristics							
Total Gate Charge	Q _G	V _{CE} =600V, I _C =40A, V _{GE} =15V		128		nC	
Gate-Emitter Charge	Q _{GE}			31		nC	
Gate-Collector Charge	Q _{GC}			69		nC	
Turn-On Delay Time	t _{DON)}	V _{CC} =600V, I _C =40A, R _G =5Ω, V _{GE} =0~15V, L=500μH		16		ns	
Rise Time	t _R			39		ns	
Turn-Off Delay Time	t _{DOFF)}			180		ns	
Fall Time	t _F			153		ns	
Turn-On Switching Loss	E _{ON}			3.5		mJ	
Turn-Off Switching Loss	E _{OFF}			3.1		mJ	
SOURCE- DRAIN DIODE RATINGS AND CHARACTERISTICS							
Forward Voltage Drop	V _F		I _F =40A			2.0	V
Reverse Recovery Time	t _{rr}	I _F =40A, di/dt=100A/μS		325		ns	
Reverse Recovery Charge	Q _{rr}				6085		nC

■ TEST CIRCUIT AND WAVEFORMS

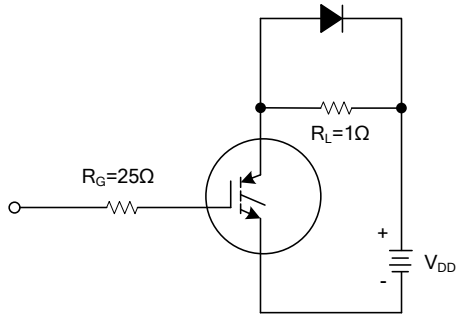


Fig 1. INDUCTIVE SWITCHING TEST CIRCUIT

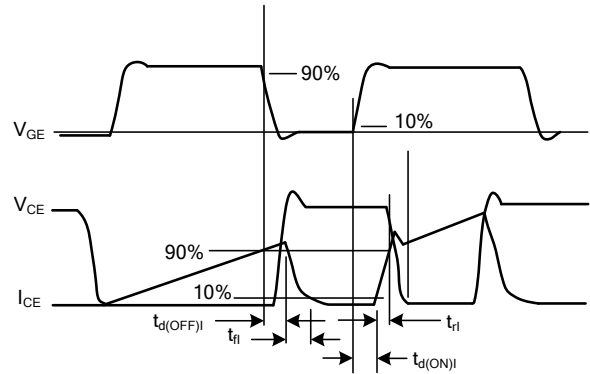
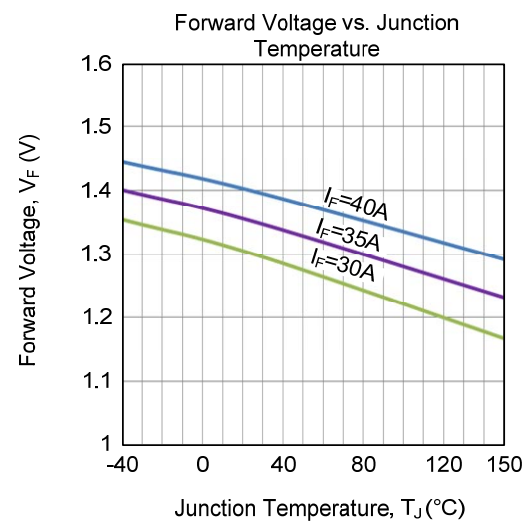
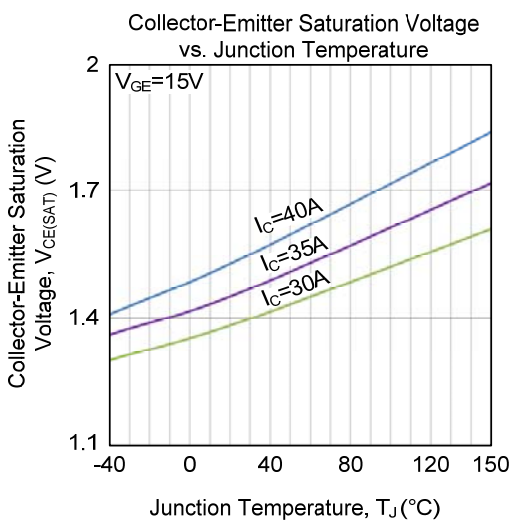
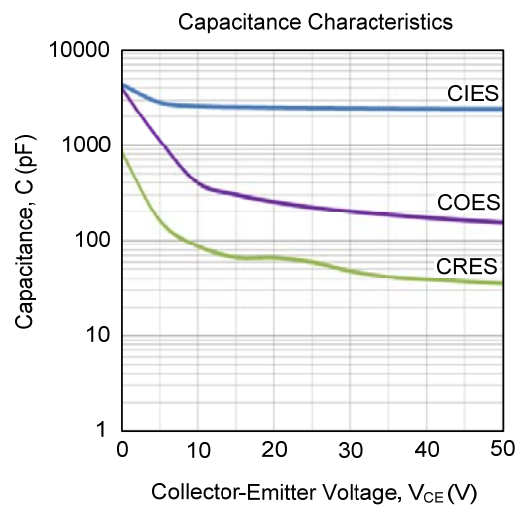
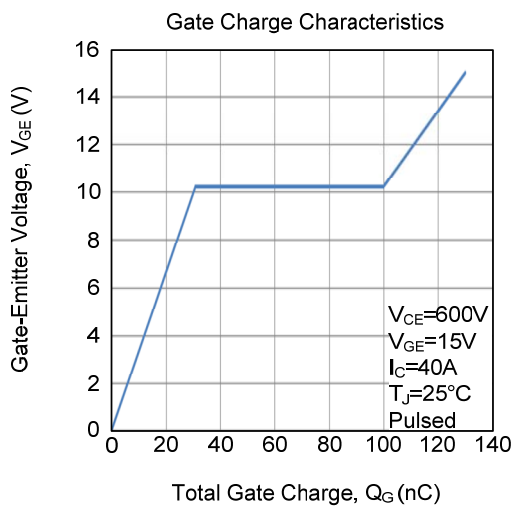
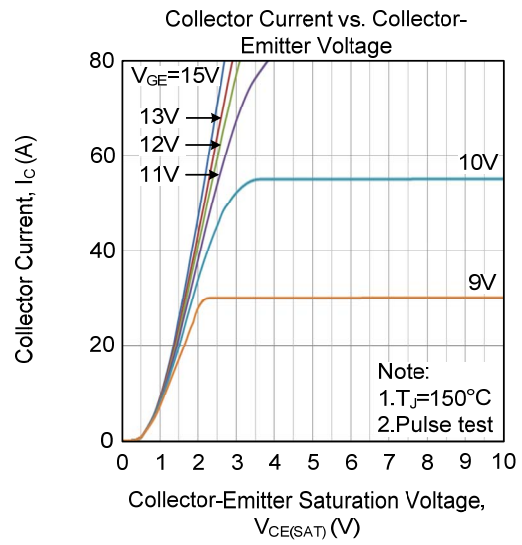
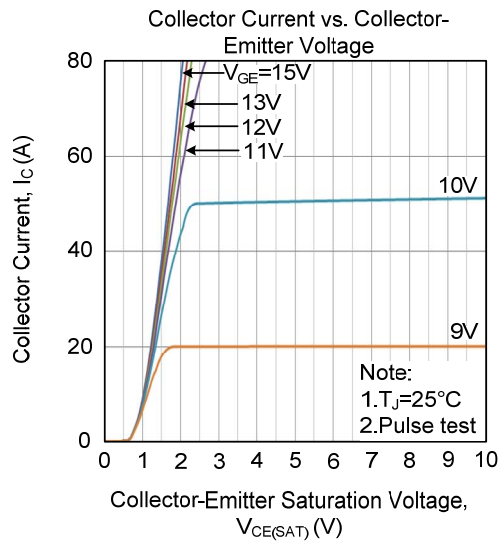
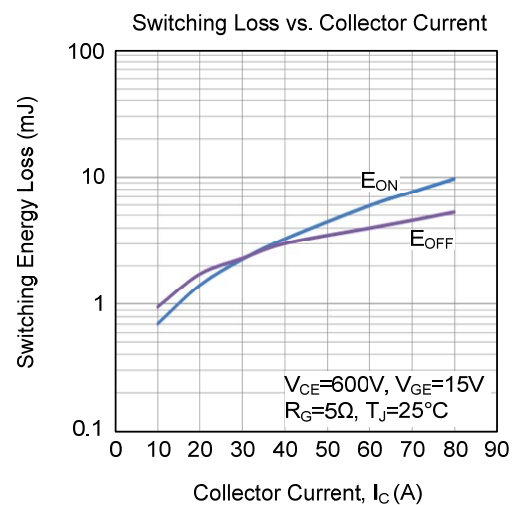
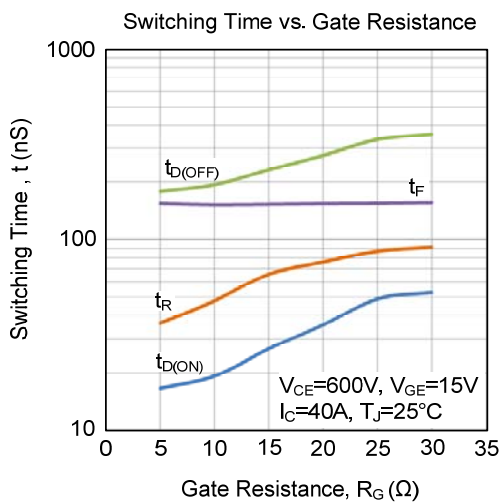
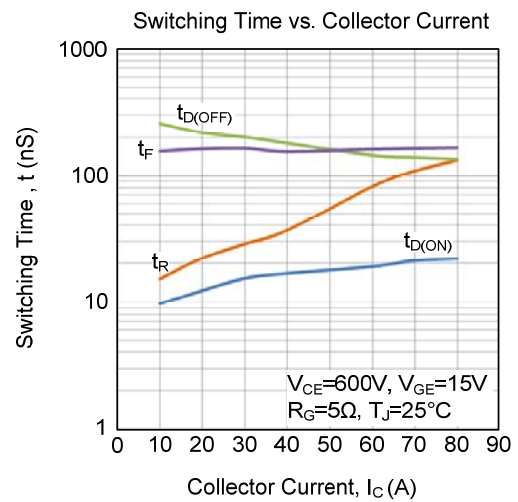
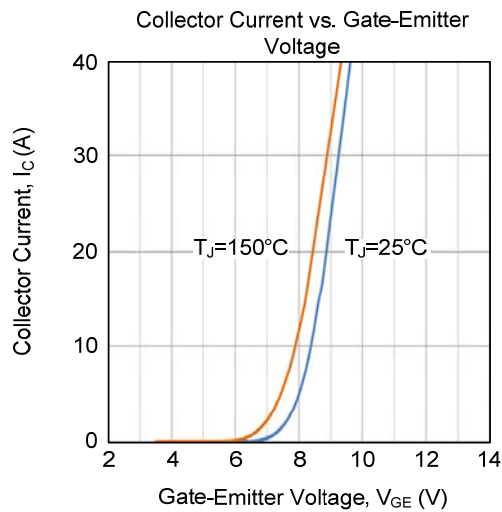
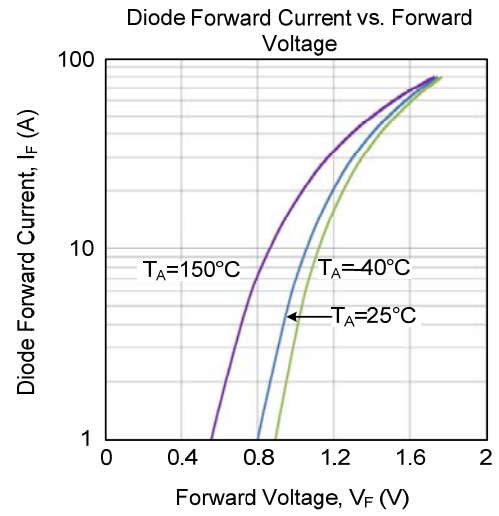
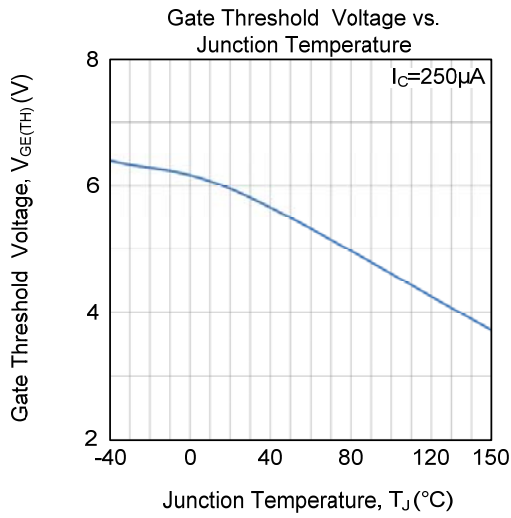


Fig 2. SWITCHING TEST WAVEFORMS

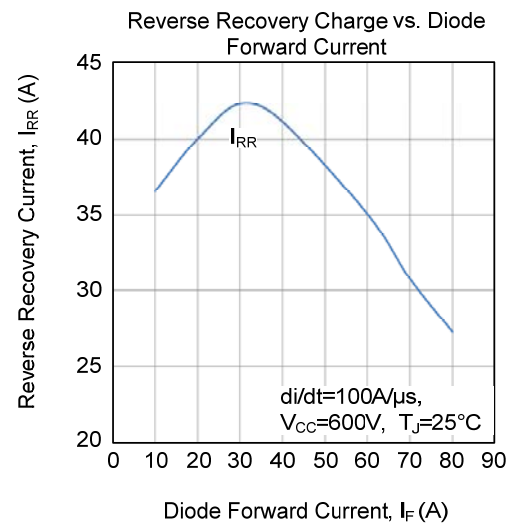
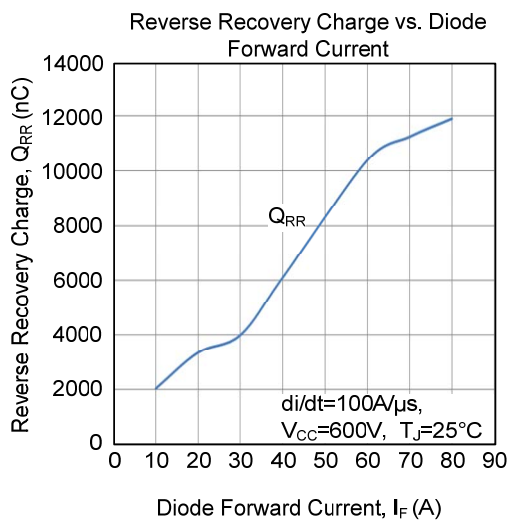
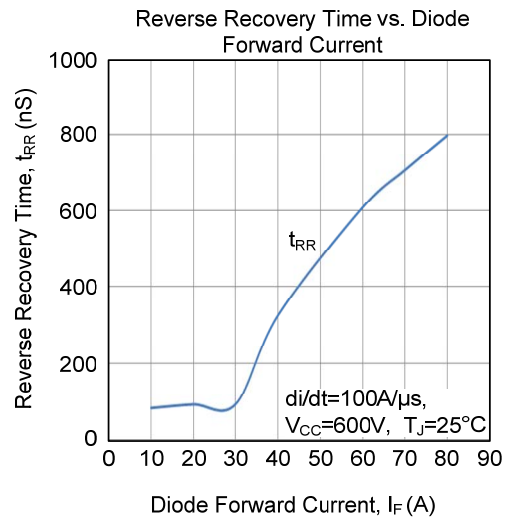
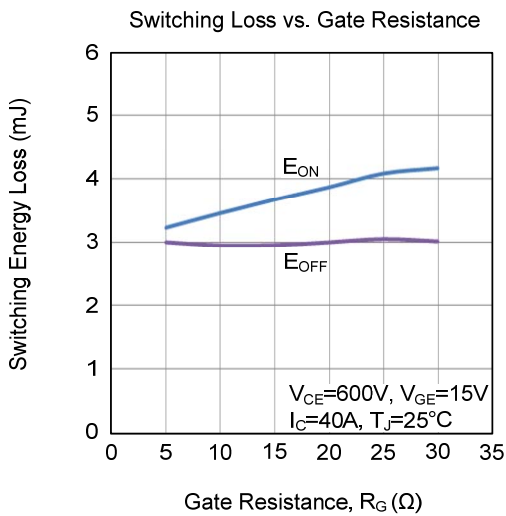
TYPICAL CHARACTERISTICS



■ TYPICAL CHARACTERISTICS (Cont.)



■ TYPICAL CHARACTERISTICS (Cont.)



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